TOSHIBA Bipolar Linear Integrated Circuit Silicon Monolithic

TA8184P,TA8184F

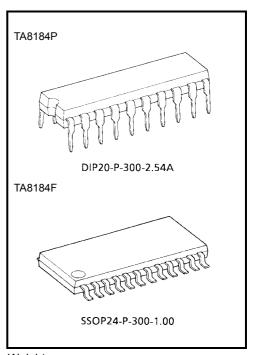
Dual Channel Voltage/Tone Control IC

The TA8184P, TA8184F is DC controlled dual volume, balance, tone (Bass and treble) IC.

It is suitable for car stereo, radio cassette, music center, TV multiplex sound receiver and remote controlled applications.

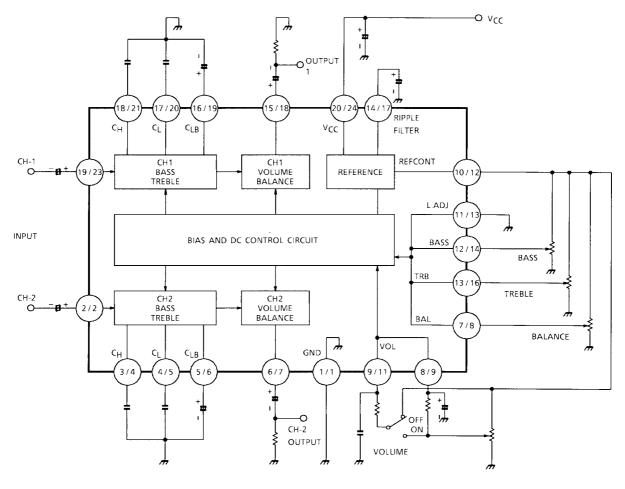
Features

- Dual channel
- Wide volume control range
 - : Maximum attenuation ATT = 100dB (typ.) (Vol. → Min, V_{IN} = 1 Vrms, BW = 400 Hz~30 kHz)
- Wide tone control range
 - : Bass $V_B = +12.5 \sim -12.5 dB$ (typ.), (f = 100 Hz)
 - : Treble VT = +12.5~-12.5dB (typ.), (f = 10 kHz)
- Built in loudness control
 - Operating supply voltage range
 - : V_{CC} (opr) = $7.5 \sim 15$ V (TA8184P) (Ta = 25° C)
 - : V_{CC} (opr) = 7.5~12.5 V (TA8184F) (Ta = 25°C)



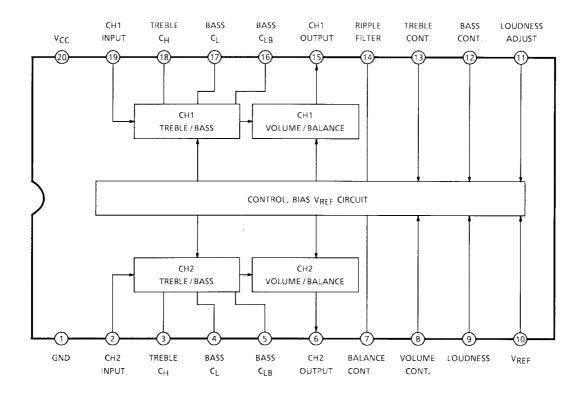
Weight DIP20-P-300-2.54A: 1.4 g (typ.) SSOP24-P-300-1.00: 0.31 g (typ.)

Block Diagram



PIN CONNECTION : (P/F) TA8184F : pin③, ⑩, ⑮, ⑳ : N.C

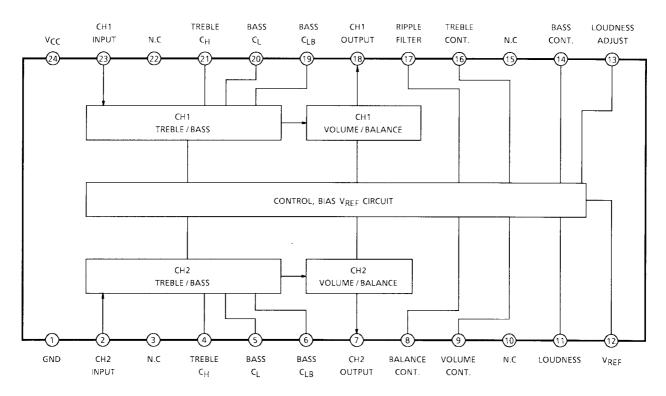
Pin Connection (TA8184P)



Pin Function

Pin No.	Symbol	Explanation	Pin No.	Symbol	Explanation	
1	GND	GND	11	L.ADJ.	Loudness adjust	
2	IN2	CH2, input	12	BASS	Bass control	
3	C _{H (2)}	CH2, treble control time constant	13	TRBL	Treble control	
4	C _{L (2)}	CH2, bass control time constant	14	RIP	Ripple filter	
5	C _{LB (2)}	CH2, bass control time constant	15	OUT1	CH1, output	
6	OUT2	CH2, output	16	C _{LB (1)}	CH1, bass control time constant	
7	BAL	Balance control	17	C _{L (1)}	CH1, bass control time constant	
8	VOL	Volume control	18	C _{H (1)}	CH1, treble control time constant	
9	LOUD	Loudness switch	19	IN1	CH1, input	
10	REF	Reference	20	V _{CC}	V _{CC}	

Pin Connection (TA8184F)



Pin Function

Pin No.	Symbol	Explanation	Pin No.	Symbol	Explanation
1	GND	GND	13	L.ADJ.	Loudness adjust
2	IN2	CH2, input	14	BASS	Bass control
3	N.C		15	N.C	
4	C _{H (2)}	CH2, treble control time constant	16	TRBL	Treble control
5	C _{L (2)}	CH2, bass control time constant	17	RIP	Ripple filter
6	C _{LB (2)}	CH2, bass control time constant	18	OUT1	CH1, output
7	OUT2	CH2, output	19	C _{LB (1)}	CH1, bass control time constant
8	BAL	Balance control	20	C _{L (1)}	CH1, bass control time constant
9	VOL	Volume control	21	C _{H (1)}	CH1, treble control time constant
10	N.C		22	N.C	
11	LOUD	Loudness switch	23	IN1	CH1, input
12	REF	Reference	24	V _{CC}	V _{CC}

Operating Precautions and Application Methods (Pin No.: (P/F))

1. How to determine tone controlled frequency characteristic time constants

Bass characteristics determining elements: CL, CLB terminals ((4/5), (5/6), (16/19), (17/20)) Figure 1 Low-bandwidth cut-off frequencies fL1, fL2, fL3 of bass characteristics are determined by the following equations:

$$f_{L1} = \frac{1}{2 \pi \cdot C_{LB} \cdot 10 \, \mathrm{k} \, \Omega} \quad \cdots (1)$$

 $(10 \text{ k}\Omega \text{ is determined in IC interior})$

$$f_{L2} = \frac{1}{2 \pi \cdot C_{LB} \cdot 1 k \Omega} \quad \dots \quad (2)$$

 $(1 \text{ k}\Omega \text{ is determined in IC interior})$

$$f_{L3} = \frac{1}{2 \pi \cdot C_L \cdot 10 \, \mathrm{k} \, \Omega} \quad \dots \quad (3)$$

 $(10 \text{ k}\Omega \text{ is determined in IC interior})$

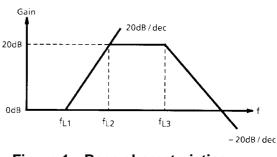


Figure 1 **Bass characteristics** (during boosting)

Under reference circuits of C_L = 0.33 μ F and C_{LB} = 10 μ F, setting is made as follows: $f_{L1}\approx 1.59~Hz,\,f_{L2}\approx 15.9~Hz,\,f_{L3}\approx 48.2~Hz$

When the characteristics during boosting are considered, crossing with 0dB axis is made at f_{L1} , increase starts by 20dB/dec., and flat characteristics of Gain = 20dB is obtained at f_{L2} .

Low-bandwidth f response is determined at fL3-namely, CL and gain starts decreasing from fL3 by -20dB /dec.

As explained above, low-bandwidth characteristics can be varied by varying CL and CLB.

Treble characteristics determining element: CH ((3/4), (18/21))

Figure 2 High-bandwidth cut-off frequencies f_{H1} and f_{H2} of treble characteristics can be determined by the following equations:

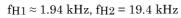
$$f_{H1} = \frac{1}{2 \pi \cdot C_H \cdot 10 \, \mathrm{k} \, \Omega} \quad \cdots \cdot (4)$$

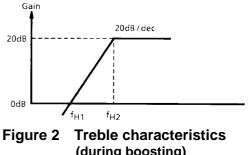
 $(10 \text{ k}\Omega \text{ is determined in IC interior})$

$$f_{H2} = \frac{1}{2 \pi \cdot C_H \cdot 1 k \Omega} \quad \dots \quad (5)$$

 $(1 \text{ k}\Omega \text{ is determined in IC interior})$

Under reference circuit of $C_{\rm H} = 0.0082 \,\mu F$ setting is made as follows:





(during boosting)

As explained above, high-bandwidth characteristics can be varied by varying CH. By creating the status of $C_L \rightarrow$ decrease and $C_H \rightarrow$ increase, low/high bandwidth gains

(f = 100 Hz, 10 kHz) increase but gain near f = 1 kHz is also increased.

On the other hand, when the status of $C_L \rightarrow$ increase and $C_H \rightarrow$ decrease is created, take note that gain near f = 1 kHz approaches 0dB while low/high-bandwidth gains are decreased.

2. Loudness control

By connecting pin (9/11) (loudness terminal) to pin (8/9) (volume terminal), "Loudness" status can be created. Loudness boost amount is determined by pin (9/11) DC voltage (refer to the subsequently described GV-V (9/11) data).

Loudness is controlled by considering that sound levels will become uniform for all frequency levels through increasing low/high-bandwidth gains when volume is reduced-namely, sound volume is low. When loudness control is not used, connect pin (9/11) to pin (10/12) (reference terminal).

The capacitor (typ. 0.047 μ F) between pin (9/11) and GND is for reducing pop sound during loudness \rightarrow ON while the capacitor (typ. 1 μ F) between pin (8/9) and GND is used for the same purpose during loudness \rightarrow OFF.

3. Loudness adjustment

When loudness is set, the boost amount can be varied by adjusting voltage at pin (11/13). Under V (11/13) = 0 V, maximum boost amount is obtained and under V (11/13) = V_{REF} (connected to pin (10/12)), minimum boost amount is obtained (refer to the subsequently described GV – V (11/13) data).

4. Relations between tone control and loudness

Because of the circuit configuration on this IC, the sum of boost amount by bass/treble control and boost amount by loudness setting is restricted to become below a constant value. Therefore, the greater the boost amount in-creases, the lower the boost amount by bass/treble control is reduced because loudness is extensively applied. As opposed to this phenomenon, on the other hand, the cut amount increases. (Refer to the subsequent descriptions on tone control frequency response during loudness.)

Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit		
Power supply voltage	TA8184P	V _{CC}	15	V	
Tower supply voltage	TA8184F	VCC	12.5		
Power dissipation	TA8184P	P _D (Note 1)	1200	mW	
	TA8184F		750 (Note 2)	IIIVV	
Operating temperature	T _{opr}	-30~85	°C		
Storage temperature	T _{stg}	-55~150	°C		

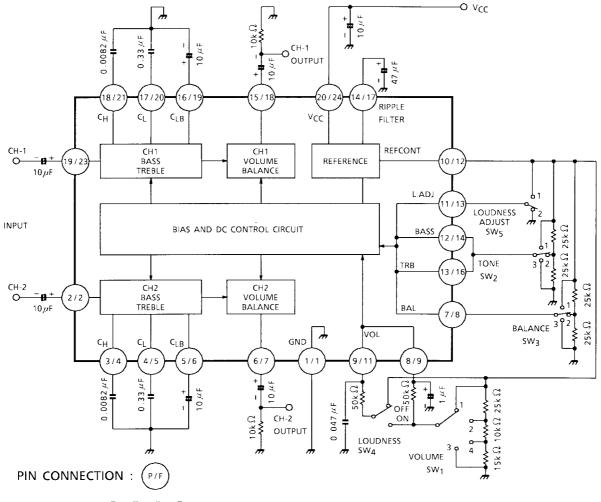
Note 1: Derated above Ta = 25° C in the proportion of 9.6 mW/°C for TA8184P, and of 6.0 mW/°C for TA8184F.

Note 2: Value for mounting on PC board (60 mm × 85 mm × 1.2 mm, Glass epoxy.)

Electrical Characteristics (unless otherwise specified, $V_{CC} = 8 V$, f = 1 kHz, Ta = 25°C)

Characteristics	Symbol	Test Circuit	Test Condition		Min	Тур.	Max	Unit
Quiescent current	Iccq	—	V _{IN} = 0		_	19	27	mA
Reference voltage	V _{ref}	—		_	4.7	5.1	5.5	V
Maximum output voltage	V _{OM}	_		Tone/Bal = Center Vol. = max, THD = 1%		1.6	-	Vrms
Voltage gain	GV	-	Tone/Bal = Center Vol. = max, V _{IN} = 0.1 Vrms		-2.0	0	2.0	dB
Maximum attenuation	ATT	-	Tone/Bal = Center BW = 400 Hz~30 kHz Vol. = min, V _{IN} = 1 Vrms		85	100	_	dB
Bass control range	V _{B MAX}	—	Tone = max	Vol. = max Bal = Center	9.5	12.5	15.5	dB
bass control range	V _{B MIN}	—	Tone = min	f_{IN} = 1 kHz \rightarrow 100 Hz V _{IN} = 0.1 Vrms	-15.5	-12.5	-9.5	
Treble control range	V _{T MAX}	_	Tone = max	Vol. = max Bal = Center	9.0	12.5	16.0	dB
	V _{T MIN}	—	Tone = min	f_{IN} = 1 kHz \rightarrow 10 kHz V _{IN} = 0.1 Vrms	-16.0	-12.5	-9.0	
Total harmonic distortion	THD	-	Tone/Bal = Center, f = 1 kHz, Vol. = max, V _{IN} = 1 Vrms		_	0.05	0.2	%
Output noise voltage	V _{NO}	_	Tone/Bal = Center BW = 20 Hz~20 kHz Vol. = min, input open		_	4	10	μVrms
Loudness control	V _{LB}	_	f = 100 Hz	$V_{IN} = 1 Vrms$		11	14	- dB
	V _{LT}	_	f = 10 Hz	Vol. = SW ₁ [4] Loudness test = SW ₅ [2]	8	11	14	

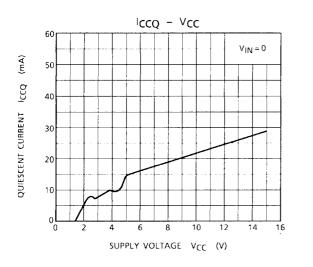
Test Circuit

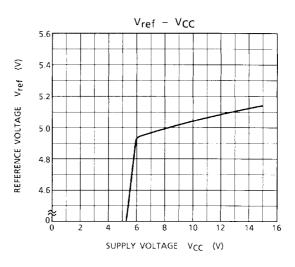


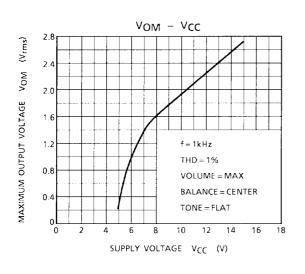
TA8184F : pin③, ⑩, ⑮, ⑫ : N.C

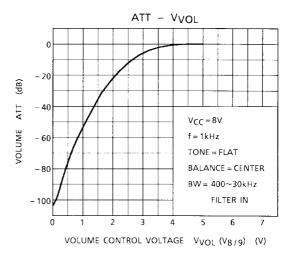
Switch Explanation

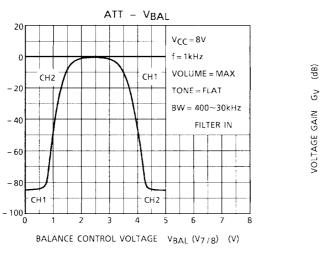
Switch Name	Position								
Switch Name	1	2	3	4	ON	OFF			
SW ₁ : Volume	max	Center	min	Loudness test	_	—			
SW ₂ : Tone	max	Center	min	—	-	—			
SW ₃ : Balance	CH2 Cut	Center	CH1 Cut	—	_	—			
SW ₄ : Loudness	_	_	_	—	Loudness ON	Loudness OFF			
SW_5 : Loudness adjust	min	max	—	—		—			





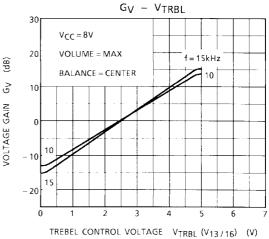


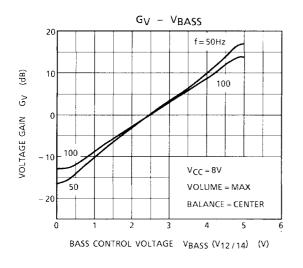


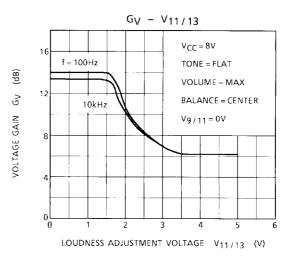


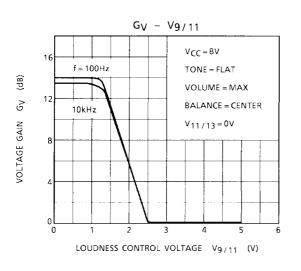
(dB)

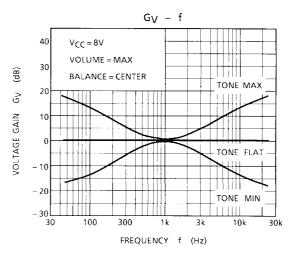
BALANCE ATT

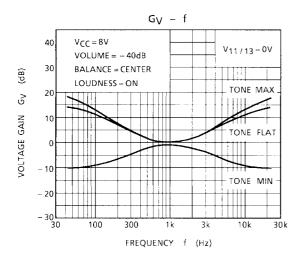


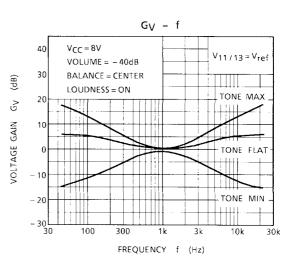


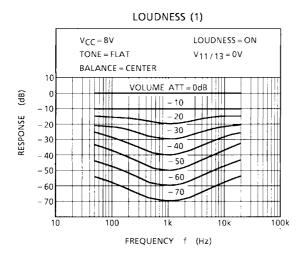


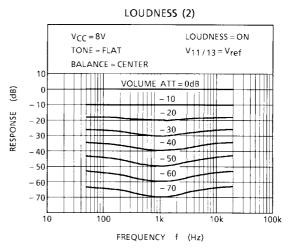


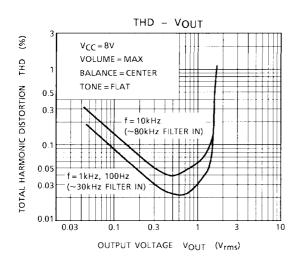


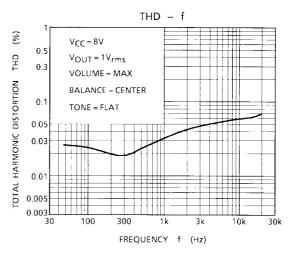


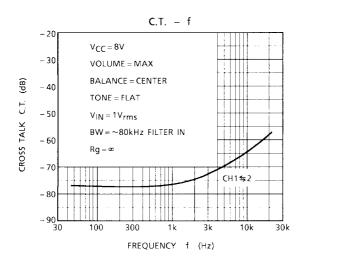


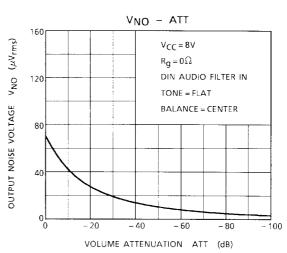










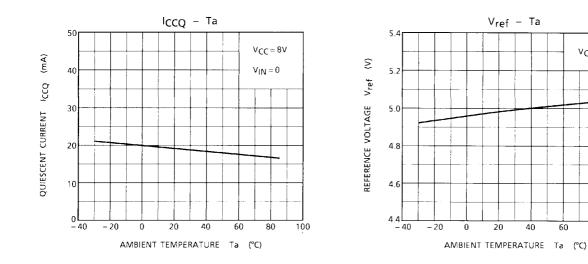


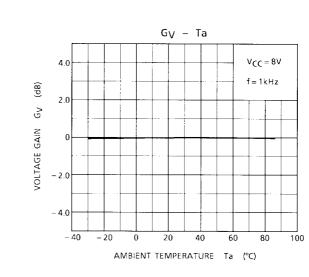
V_{CC} = 8V

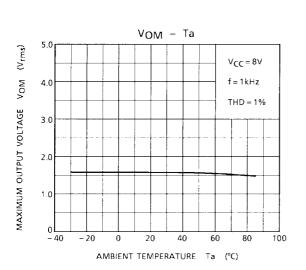
60

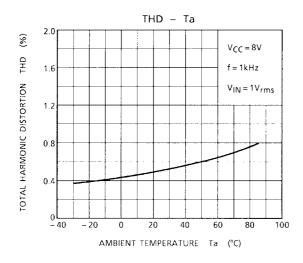
80

100

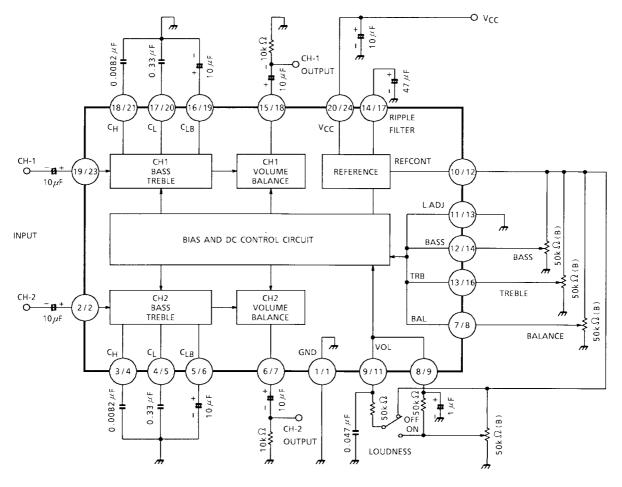








Application

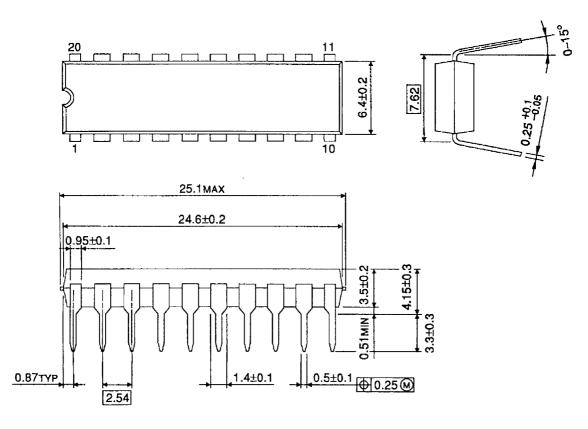


PIN CONNECTION : (P/F) TA8184F : pin③, ⑩, ⑮, ⑳ : N.C

Package Dimensions

DIP20-P-300-2.54A

Unit : mm

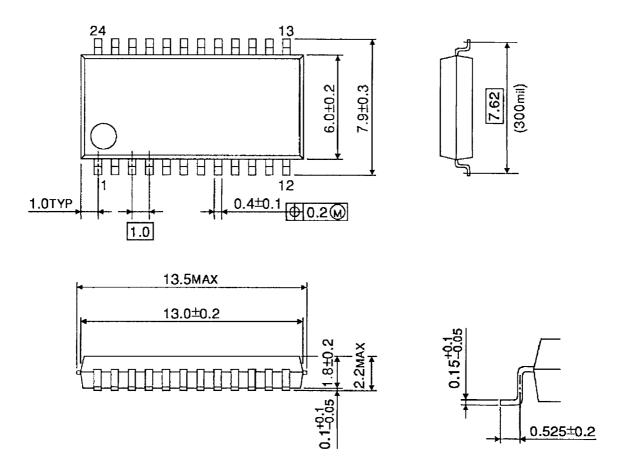


Weight: 1.4 g (typ.)

Package Dimensions

SSOP24-P-300-1.00

Unit : mm



Weight: 0.31 g (typ.)

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